NPN Epitaxial Planar Silicon Transistor



15C02MH

Low-Frequency General-Purpose Amplifier Applications

An ON Semiconductor Company

Applications

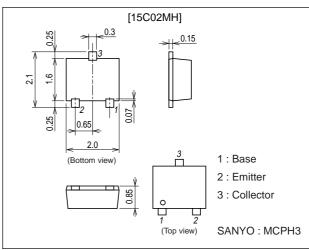
• Low-frequency amplifer, high-speed switching, small motor drive.

Features

- Large current capacitance.
- Low collector-to-emitter saturation voltage (resistance). RCE(sat) typ= $300m\Omega[IC=1A, IB=50mA]$.
- Ultrasmall package facilitates miniaturization in end products.
- Small ON-resistance (Ron).

Package Dimensions

2194A



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		20	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		1	А
Collector Current (Pulse)	ICP		2	А
Collector Dissipation	PC	Mounted on a ceramic board (600mm ² X0.8mm)	600	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =12V, I _E =0			100	nA
Emitter Cutoff Current	IEBO	VEB=4V, IC=0			100	nA
DC Current Gain	hFE	V _{CE} =2V, I _C =50mA	300		800	
Gain-Bandwidth Product	fT	V _{CE} =2V, I _C =50mA		440		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		4		pF
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	IC=400mA, IB=20mA		140	280	mV
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	IC=400mA, IB=20mA		0.9	1.2	V
Marking : CK	vBE(sat)	IC=400IIA, IB=20IIA			1.2	v

Marking : CK

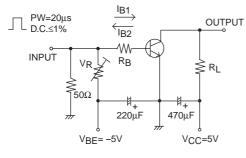
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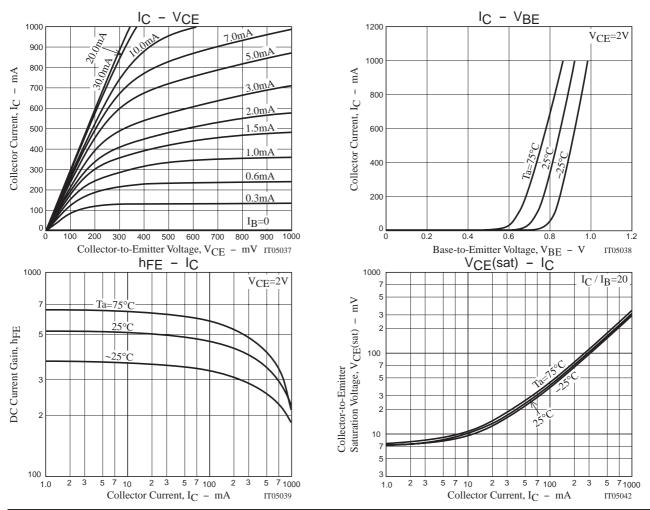
SANYO Electric Co., Ltd. Semiconductor Company TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10μA, IE=0	20			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0	5			V
Turn-ON Delay Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		165		ns
Turn-OFF Delay Time	tf	See specified Test Circuit.		25		ns

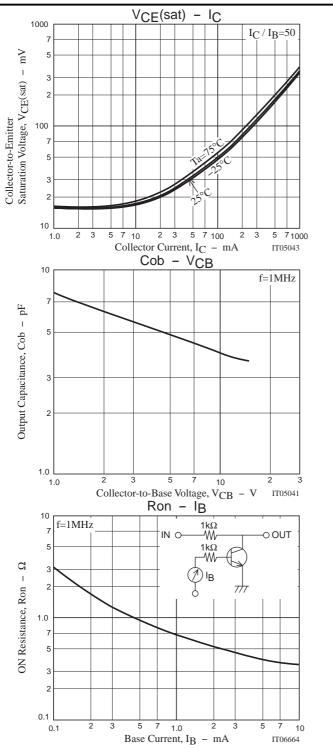
Switching Time Test Circuit

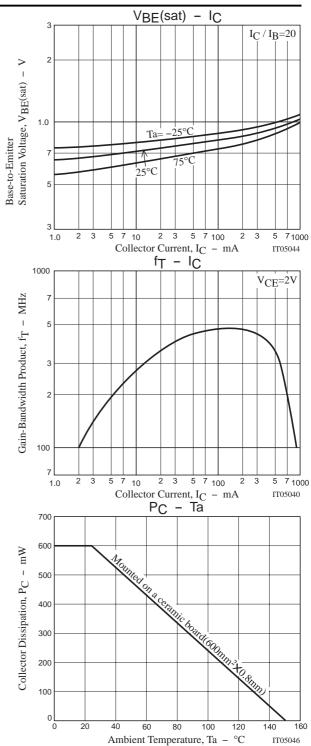


 $I_{C}=20I_{B1}=-20I_{B2}=400mA$



No.7354-2/4





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